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ON Semiconductor®

FDB86566-F085

N-Channel PowerTrench® MOSFET **60 V, 110 A, 2.7 m**Ω

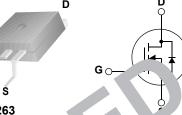
Features

- Typical $R_{DS(on)}$ = 2.2 m Ω at V_{GS} = 10V, I_D = 80 A
- Typical $Q_{g(tot)}$ = 80 nC at V_{GS} = 10V, I_D = 80 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems





unless scherwise noted. **MOSFET Maximum Rating**

Symbol	rameter	Ratings	Units
V_{DSS}	Drain-to-Sr , ce Voltage	60	V
V_{GS}	Gate-to-Scrice Volta :	±20	V
	r un currei Cont uous (V _{GS} =10) (Note 1) T _C =25°C	110	Α
ID	n Current 7 _C = 25°C	See Figure 4	_ A
FAS	Single Pi [*] Avalanch & Energy (Note 2)	193	mJ
1p	'owe, Dissipation	176	W
P_{D}	L _rate Abo re 2 ^{r,o} C	1.2	W/°C
T_{J}, T_{G}	Operating and Stolage Temperature	-55 to + 175	οС
· JC	Thermal Resistance, Junction to Case	0.85	°C/W
$R_{\theta J \Lambda}$	Maximum 1 hermal Resistance, Junction to Ambient (Note 3)	43	°C/W

- Current is limited by 50 no vire configuration.
 Starting T_J = 25°C, L = 50µH, I_{AS} = 88A, V_{DD} = 60V during inductor charging and V_{DD} = 0V during time in avalanche.
- 3: R_{0,IA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB86566	FDB86566-F085	D2-PAK(TO-263)	330mm	24mm	800 units

Units

Max.

Electrical Characteristics $T_J = 25$ °C unless otherwise noted.

Parameter

Off Ch	aracteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	$I_D = 250 \mu A$	V _{GS} = 0V	60	-	-	٧
I _{DSS}	Drain-to-Source Leakage Current	V _{DS} =60V,	$T_{\rm J} = 25^{\rm o}{\rm C}$	-	-	1	μА
		$V_{GS} = 0V$	$T_J = 175^{\circ}C \text{ (Note 4)}$	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$	•	-	-	±100	nA

Test Conditions

Min.

Тур.

On Characteristics

Symbol

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$		2.0	3 ^		V
R _{DS(on)}	Drain to Source On Resistance	I _D = 80A,	$T_{\rm J} = 25^{\rm o}{\rm C}$	1	2.	2.,	mΩ
		V _{GS} = 10V	$T_J = 175^{\circ}C \text{ (Note 4)}$		4.1	5.0	mΩ

Dynamic Characteristics

				1
C _{iss}	Input Capacitance	V = 20 V V = 0	ა655 -	pF
C _{oss}	Output Capacitance	V _{DS} = 30 V, V _{GS} = 0V, f = 1MHz	1745 -	pF
C _{rss}	Reverse Transfer Capacitance	- 11/11/2	57 -	pF
R_g	Gate Resistance	f = 1MH	2.2	Q
$Q_{g(ToT)}$	Total Gate Charge at 10V	V _C 1 to 10 = 30½	80 110	UC.
$Q_{g(th)}$	Threshold Gate Charge	$V_{GS} = 2V$ $I_D = 85A$ -	9 4	nC
Q_{gs}	Gate-to-Source Gate Charge	1000	35	nC
Q_{gd}	Gate-to-Drain "Miller" Charge	NV IR-	10 -	nC

Switching Characteristic

t _{on}	Turn-On Tir	-	-	115	ns
t _{d(on)}	Turn-On [lay	-	36	-	ns
t _r	$V_{DD} = 30 \text{ V, } I_D = 80 \text{A,}$	-	52	-	ns
$t_{d(off)}$	urn-O" Deic $V_{33} = 10V, R_{GEN} = 6\Omega$	-	36	-	ns
t _f	I TIME	-	13	-	ns
	Tu of .ime	-	-	64	ns

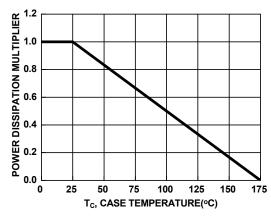
Drai. So. ce Dicge Characterisacs

	Source-to-Prain Dicue Voltage	I_{SD} =80A, V_{GS} = 0V	-	-	1.25	V
70	Scurse-to-1 . a. (i Disue voltage	I_{SD} = 40A, V_{GS} = 0V	1	-	1.2	V
t _{ee}	Reverse-Recovery Time	$I_F = 80A$, $dI_{SD}/dt = 100A/\mu s$,	1	78	102	ns
O ^{tt}	Reverse-Recovary Charge	V _{DD} =48V	-	100	130	nC

Note:

4: The maximum value \bowtie specified by design at T_J = 175°C. Product is not tested to this condition in production.

Typical Characteristics



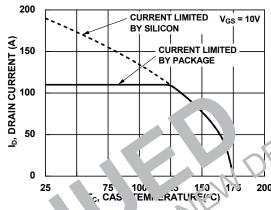
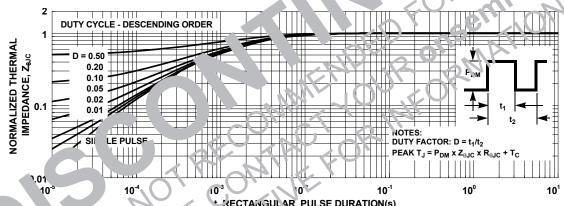


Figure 1. Normalized Power Dissipation vs. Case Temperature

Figr 2. M. rim finitious Drain Current vs.

Case Temperature



RECTANGULAR PULSE DURATION(s)
Figure 3. Morgialized Maximum Transient Thermal Impedance

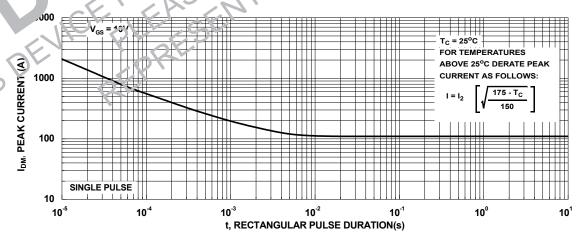


Figure 4. Peak Current Capability

Typical Characteristics

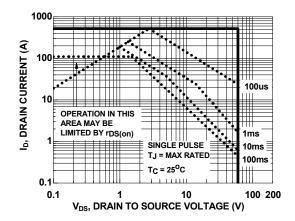
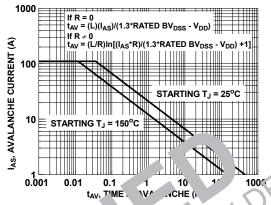
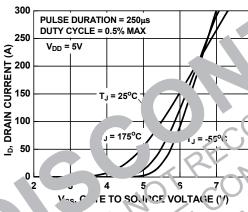


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to ON Sem. nduc Applir on Note: AN75 \downarrow 4 and AN7515

Figure Un ampe Inductive Switching



F. re 7. Transfer Characteristics

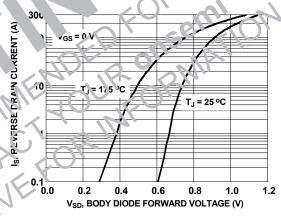


Figure 8. Forward Diode Characteristics

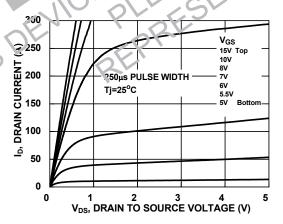


Figure 9. Saturation Characteristics

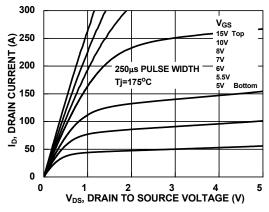


Figure 10. Saturation Characteristics

Typical Characteristics

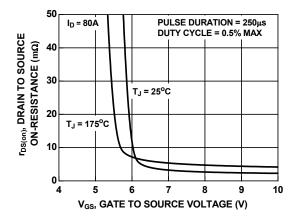


Figure 11. R_{DSON} vs. Gate Voltage

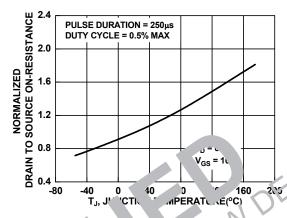
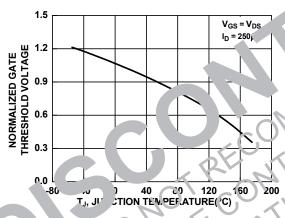


Figure 12 Norma rea SON vs. Junction Ten grature



Figu 15 lormalized Gate Threshold Voltage vs.

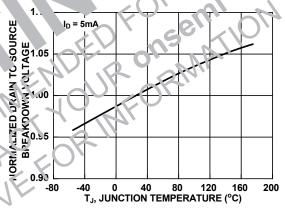


Figure 14. Normalized Drain to Source Breakdown Voltage vs. Junction Temperature

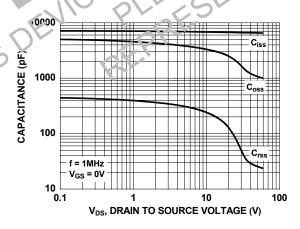


Figure 15. Capacitance vs. Drain to Source Voltage

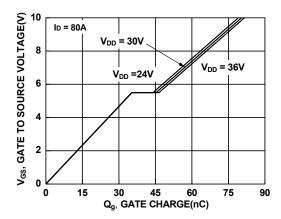


Figure 16. Gate Charge vs. Gate to Source Voltage



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